

### **KSC1815**

# Audio Frequency Amplifier & High Frequency OSC

- Complement to KSA1015
- Collector-Base Voltage : V<sub>CBO</sub>= 50V



# **NPN Epitaxial Silicon Transistor**

### **Absolute Maximum Ratings** $T_a$ =25°C unless otherwise noted

Symbol	Parameter	Value	Units
$V_{CBO}$	Collector-Base Voltage	60	V
$V_{CEO}$	Collector-Emitter Voltage	50	V
$V_{EBO}$	Emitter-Base Voltage	5	V
I <sub>C</sub>	Collector Current	150	mA
I <sub>B</sub>	Base Current	50	mA
P <sub>C</sub>	Collector Power Dissipation	400	mW
T <sub>J</sub>	Junction Temperature	125	°C
T <sub>STG</sub>	Storage Temperature	-55 ~ 150	°C

### **Electrical Characteristics** $T_a$ =25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
I <sub>CBO</sub>	Collector Cut-off Current	$V_{CB}=60V, I_{E}=0$			0.1	μΑ
I <sub>EBO</sub>	Emitter Cut-off Current	$V_{EB}$ =5V, $I_{C}$ =0			0.1	μΑ
h <sub>FE1</sub> h <sub>FE2</sub>	DC Current Gain	V <sub>CE</sub> =6V, I <sub>C</sub> =2mA V <sub>CE</sub> =6V, I <sub>C</sub> =150mA	70 25		700	
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	I <sub>C</sub> =100mA, I <sub>B</sub> =10mA		0.1	0.25	V
V <sub>BE</sub> (sat)	Base-Emitter Saturation Voltage	I <sub>C</sub> =100mA, I <sub>B</sub> =10mA			1.0	V
f <sub>T</sub>	Current Gain Bandwidth Product	V <sub>CE</sub> =10V, I <sub>C</sub> =1mA	80			MHz
C <sub>ob</sub>	Output Capacitance	V <sub>CB</sub> =10V, I <sub>E</sub> =0, f=1MHz		2.0	3.0	pF
NF	Noise Figure	$V_{CE}$ =6V, $I_{C}$ =0.1mA $R_{S}$ =10k $\Omega$ , f=1Hz		1.0	1.0	dB

## **h**<sub>FE</sub> Classification

Classification	0	Υ	GR	L
h <sub>FE1</sub>	70 ~ 140	120 ~ 240	200 ~ 400	350 ~ 700

# **Typical Characteristics**

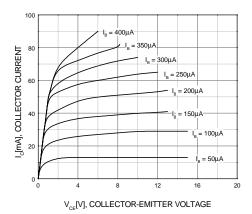


Figure 1. Static Characteristic

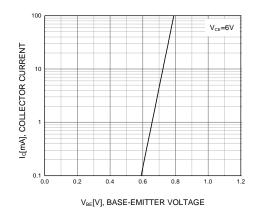


Figure 2. Transfer Characteristic

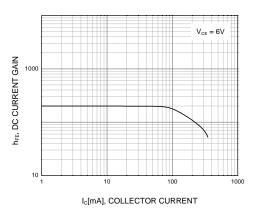


Figure 3. DC current Gain

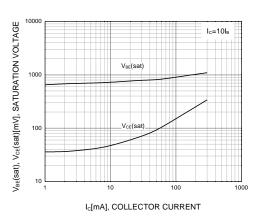


Figure 4. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

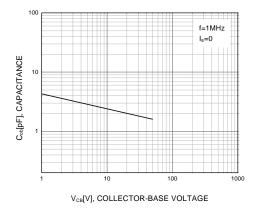


Figure 5. Output Capacitance

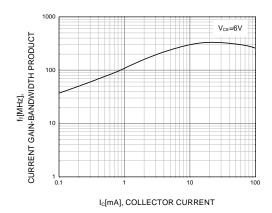
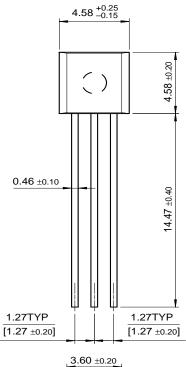


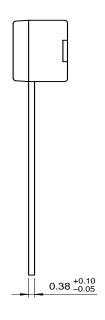
Figure 6. Current Gain Bandwidth Product

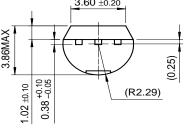
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# **Package Dimensions**

TO-92







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CROSSVOLT™	FRFET™	MicroPak™	QFET™	SuperSOT™-8
DOME™	GlobalOptoisolator™	MICROWIRE™	QS™	SyncFET™
EcoSPARK™	GTO™	MSX™	QT Optoelectronics™	TinyLogic™
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EnSigna™	$I^2C^{TM}$	$OCX^{TM}$	RapidConfigure™	UHC™
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The Power Franchise™		OPTOLOGIC <sup>®</sup>	SILENT SWITCHER®	$VCX^{TM}$
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